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SEMICONDUCTOR

# 74LVX240 Low Voltage Octal Buffer/Line Driver with 3-STATE Outputs

### **General Description**

The LVX240 is an octal inverting buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter or receiver which provides improved PC board density. The inputs tolerate up to 7V allowing interface of 5V systems to 3V systems.

- Features
- Input voltage translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

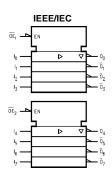
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Revised March 1999

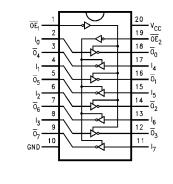
### **Ordering Code:**

Order Number	Package Number	Package Description						
74LVX240M	M20B	20-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-130, 0.300" Wide						
74LVX240SJ	M20D	20-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide						
74LVX240MTC	MTC20	20-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide						
Devices also available	Devices also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering code.							

### Logic Symbol



### **Connection Diagram**



### **Pin Descriptions**

Pin Names	Description
$\overline{OE}_1, \overline{OE}_2$	3-STATE Output Enable Inputs
I <sub>0</sub> —I <sub>7</sub>	Inputs
$\overline{O}_0 - \overline{O}_7$	Outputs

### **Truth Tables**

Inp	Outputs				
OE <sub>1</sub>	I <sub>n</sub>	- (Pins 12, 14, 16, 18)			
L	L	н			
L	Н	L			
Н	Х	Z			
Inp	Outputs				
OE <sub>2</sub>	I <sub>n</sub>	(Pins 3, 5, 7, 9)			
L	L	Н			
L	Н	L			
н	х	z			

X = Immaterial Z = High Impedance

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# Absolute Maximum Ratings(Note 1)

Supply Voltage (V <sub>CC</sub> )	-0.5V to +7.0V
DC Input Diode Current (I <sub>IK</sub> )	
$V_{I} = -0.5V$	–20 mA
DC Input Voltage (VI)	-0.5V to 7V
DC Output Diode Current (I <sub>OK</sub> )	
$V_0 = -0.5V$	–20 mA
$V_O = V_{CC} + 0.5V$	+20 mA
DC Output Voltage (V <sub>O</sub> )	–0.5V to $V_{CC}$ + 0.5V
DC Output Source	
or Sink Current (I <sub>O</sub> )	±25 mA
DC V <sub>CC</sub> or Ground Current	
(I <sub>CC</sub> or I <sub>GND</sub> )	±75 mA
Storage Temperature (T <sub>STG</sub> )	-65°C to +150°C
Power Dissipation (P <sub>D</sub> )	180 mW

# Recommended Operating Conditions (Note 2)

Supply Voltage (V <sub>CC</sub> )	2.0V to 3.6V
Input Voltage (V <sub>I</sub> )	0V to 5.5V
Output Voltage (V <sub>O</sub> )	0V to $V_{CC}$
Operating Temperature (T <sub>A</sub> )	$-40^{\circ}C$ to $+85^{\circ}C$
Input Rise and Fall Time ( $\Delta t/\Delta V$ )	0 ns/V to 100 ns/V

Note 1: Absolute Maximum Ratings are those values beyond which the safety to the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

# **DC Electrical Characteristics**

Symbol	Parameter	Vcc	T <sub>A</sub> = +25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions		
Gymbol	i arameter	•	Min	Тур	Max	Min	Max	Onita	Cond	litoria
VIH	HIGH Level	2.0	1.5			1.5				
	Input Voltage	3.0	2.0			2.0		V		
		3.6	2.4			2.4				
VIL	LOW Level	2.0			0.5		0.5			
	Input Voltage	3.0			0.8		0.8	V		
		3.6			0.8		0.8			
V <sub>OH</sub>	HIGH Level	2.0	1.9	2.0		1.9			$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OH</sub> = -50 μA
	Output Voltage	3.0	2.9	3.0		2.9		V		$I_{OH} = -50 \ \mu A$
		3.0	2.58			2.48				$I_{OH} = -4 \text{ mA}$
V <sub>OL</sub>	LOW Level	2.0		0.0	0.1		0.1		$V_{IN} = V_{IH} \text{ or } V_{IL}$	I <sub>OL</sub> = 50 μA
	Output Voltage	3.0		0.0	0.1		0.1	V		$I_{OL} = 50 \ \mu A$
		3.0			0.36		0.44			$I_{OL} = 4 \text{ mA}$
I <sub>OZ</sub>	3-STATE Output	3.6			±0.25		±2.5	μΑ	$V_{IN} = V_{IH} \text{ or } V_{IL}$	•
	Off-State Current								$V_{OUT} = V_{CC}$ or G	ND
I <sub>IN</sub>	Input Leakage Current	3.6			±0.1	1	±1.0	μA	V <sub>IN</sub> = 5.5V or GND	
Icc	Quiescent Supply Current	3.6			4.0		40.0	μA	$V_{IN} = V_{CC} \text{ or } GN$	D

## Noise Characteristics (Note 3)

Symbol	Parameter	V <sub>cc</sub>	T <sub>A</sub> =	25°C	Units	C <sub>L</sub> (pF)	
		(V)	Тур	Limit	•		
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	0.5	0.8	V	50	
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	-0.5	-0.8	V	50	
VIHD	Minimum HIGH Level Dynamic Input Voltage	3.3		2.0	V	50	
V <sub>ILD</sub>	Maximum LOW Level Dynamic Input Voltage			0.8	V	50	

Note 3: (Input  $t_r = t_f = 3 \text{ ns}$ )

# **AC Electrical Characteristics**

Symbol	Parameter	V <sub>CC</sub>	$T_A = +25^{\circ}C$		T <sub>A</sub> = −40°C to +85°C		Units	Conditions	
•		(V)	Min	Тур	Max	Min	Max	-	
t <sub>PLH</sub>	Propagation	2.7		5.7	10.1	1.0	12.5		C <sub>L</sub> = 15 pF
t <sub>PHL</sub>	Delay Time			8.2	13.6	1.0	16.0		C <sub>L</sub> = 50 pF
		$3.3\pm 0.3$		4.3	6.2	1.0	7.5	ns	C <sub>L</sub> = 15 pF
				6.8	9.7	1.0	11.0		C <sub>L</sub> = 50 pF
t <sub>PZL</sub>	3-STATE Output	2.7		7.1	13.8	1.0	16.5		$C_L = 15 \text{ pF}, R_L = 1 \text{ k}\Omega$
t <sub>PZH</sub>	Enable Time			9.6	17.3	1.0	20.0		$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$
		$3.3\pm 0.3$		5.5	8.8	1.0	10.5	ns	$C_L = 15 \text{ pF}, R_L = 1 \text{ k}\Omega$
				8.0	12.3	1.0	14.0		$C_L = 50 \text{ pF}, R_L = 1 \text{ k}\Omega$
t <sub>PLZ</sub>	3-STATE Output	2.7		11.6	16.0	1.0	19.0		$C_L = 50 \text{ pF}, R_L = 1  k\Omega$
t <sub>PHZ</sub>	Disable Time	$3.3\pm 0.3$		9.7	11.4	1.0	13.0	ns	$C_L = 50 \text{ pF}, R_L = 1  k\Omega$
t <sub>OSLH</sub>	Output to Output	2.7			1.5		1.5		C <sub>L</sub> = 50 pF
t <sub>OSHL</sub>	Skew (Note 4)	3.3			1.5		1.5	ns	

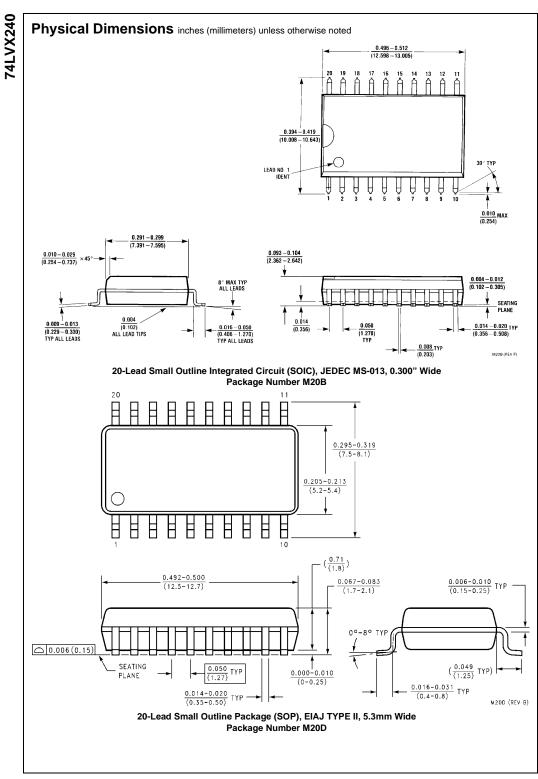
Note 4: Parameter guaranteed by design.  $t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|$ 

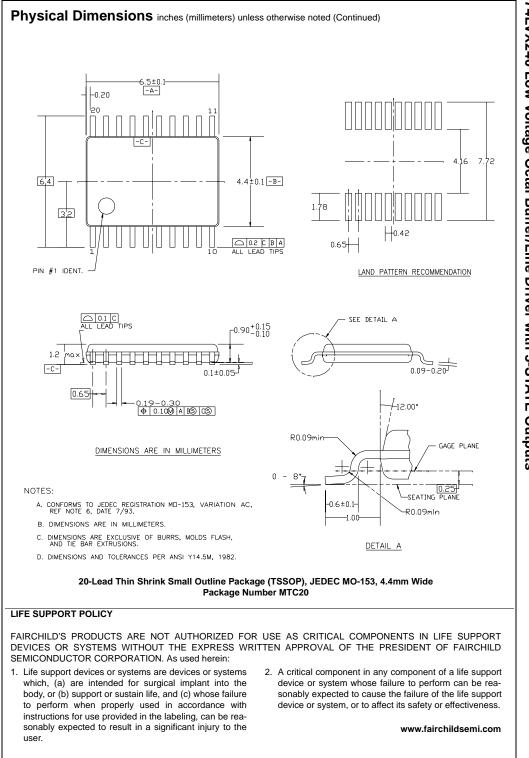
# Capacitance

Symbol	Parameter		T <sub>A</sub> = +25°C		$T_A = -40^{\circ}C$	Units	
Symbol	Falameter	Min	Тур	Max	Min	Max	Units
CIN	Input Capacitance		4	10		10	pF
COUT	Output Capacitance		6				pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)		17	10			pF
Note 5: C <sub>F</sub>	pD is defined as the value of the internal equivalent capacitance which is cal	culated from	the operatir	ng current c	onsumption w	vithout load.	

C<sub>PD</sub> is ng c

Average operating current can be obtained by the equation:  $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} + I_{CC}}{8 \text{ (per bit)}}$ 





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